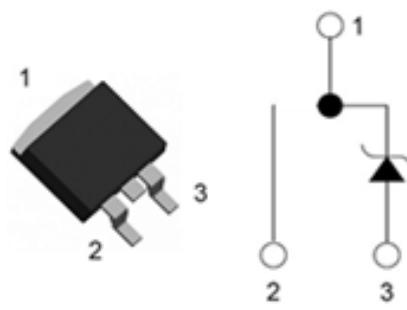


## Product Summary

$V_R = 650 \text{ V}$   
 $I_F = 10\text{A} (T_c=150^\circ\text{C})$   
 $Q_c = 23\text{nC} (V_R=400\text{V})$



**D<sup>2</sup>PAK**  
TO-263-2L

## Features

- Zero Forward/Reverse Recovery Current
- High Blocking Voltage
- High Frequency Operation
- Positive Temperature Coefficient on  $V_F$
- Temperature Independent Switching Behavior
- High surge current capability

## Applications

- Motor Drives
- Solar
- AC/DC converters
- DC/DC converters
- Uninterruptable power supplies

## Maximum Ratings

( $T_c=25^\circ\text{C}$  unless otherwise specified)

Parameter	Symbol	Test conditions	Value	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$		650	V
Peak Reverse Surge Voltage	$V_{RSM}$		650	V
DC Blocking Voltage	$V_R$		650	V
Continuous Forward Current	$I_F$	$T_c=25^\circ\text{C}$ $T_c=135^\circ\text{C}$ $T_c=150^\circ\text{C}$	32 14 10	A
Non repetitive Forward Surge Current	$I_{FSM}$	$T_c = 25^\circ\text{C}, t_p=10 \text{ ms},$ Half Sine Pulse $T_c = 110^\circ\text{C}, t_p=10 \text{ ms},$ Half Sine Pulse $T_c = 25^\circ\text{C}, t_p=10 \mu\text{s},$ Square	65 55 520	A
Repetitive peak Forward Surge Current	$I_{FRM}$	$T_c = 25^\circ\text{C}, t_p=10 \text{ ms},$ Freq = 0.1Hz, 100 cycles, Half Sine Pulse $T_c = 110^\circ\text{C}, t_p=10 \text{ ms},$ Freq = 0.1Hz, 100 cycles, Half Sine Pulse	55 45	A
Total power dissipation	$P_D$	$T_c=25^\circ\text{C}$	94	W
Operating Junction Temperature	$T_J$		-55 to 175	°C
Storage Temperature	$T_{STG}$		-55 to 175	°C

## Benefits

- Higher System Efficiency
- Parallel Device Convenience without thermal runaway
- Higher Temperature Application
- No Switching loss
- Hard Switching & Higher Reliability
- Environmental Protection

**Electrical Characteristics**

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
DC Blocking Voltage	$V_{DC}$	$I_R = 250\mu A, T_J = 25^\circ C$	650			V
Forward Voltage	$V_F$	$I_F = 10A, T_J = 25^\circ C$		1.45	1.8	V
		$I_F = 10A, T_J = 125^\circ C$		1.6		
		$I_F = 10A, T_J = 175^\circ C$		1.7		V
Reverse Current	$I_R$	$V_R = 650V, T_J = 25^\circ C$		12	80	uA
		$V_R = 650V, T_J = 125^\circ C$		68		uA
		$V_R = 650V, T_J = 175^\circ C$		190		uA
Total Capacitive Charge	$Q_C$	$V_R = 400V, I_F = 10A, di/dt = 200A/us, T_J = 25^\circ C$		23		nC
Total Capacitance	C	$V_R = 1V, T_J = 25^\circ C, Freq = 1MHz$		380		
		$V_R = 200V, T_J = 25^\circ C, Freq = 1MHz$		48		pF
		$V_R = 400V, T_J = 25^\circ C, Freq = 1MHz$		31		

Note: This is a majority carrier diode, so there is no reverse recovery charge

**Thermal Characteristics**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Thermal Resistance	$R_{th(j-c)}$	junction-case		1.6		°C/W

## Typical Electrical Curves

Figure 1. Forward Characteristics

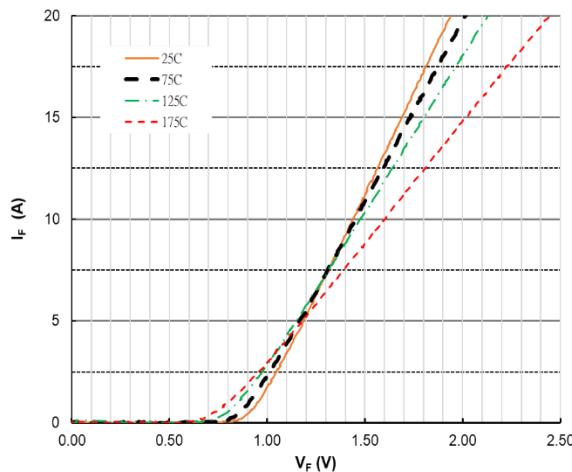


Figure 2. Forward Characteristics

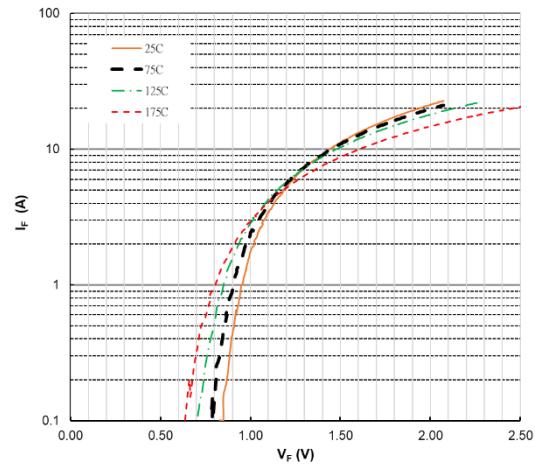


Figure 3. Reverse Characteristics

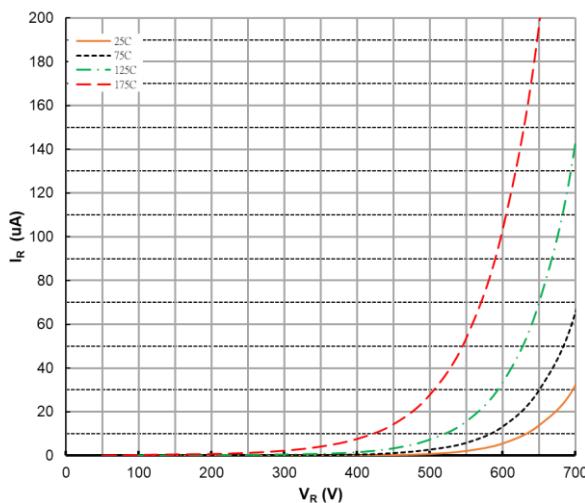


Figure 4. Power Derating

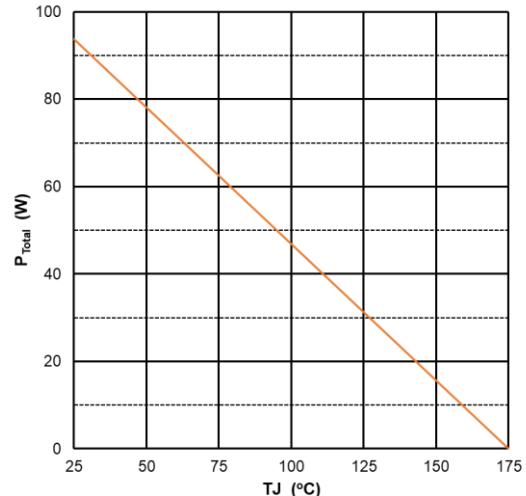


Figure 5. Capacitance vs Reverse Voltage

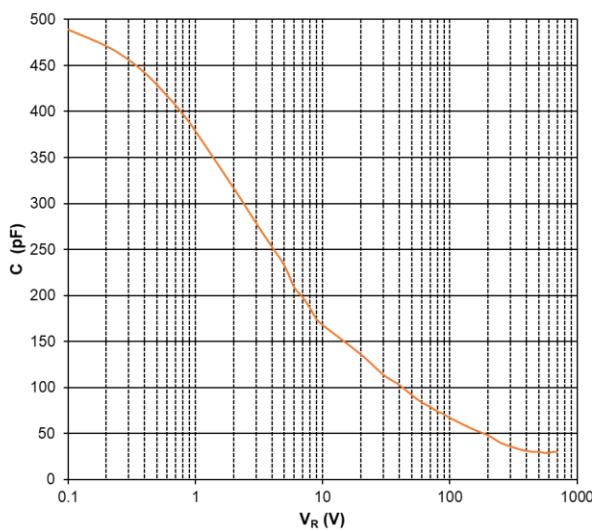
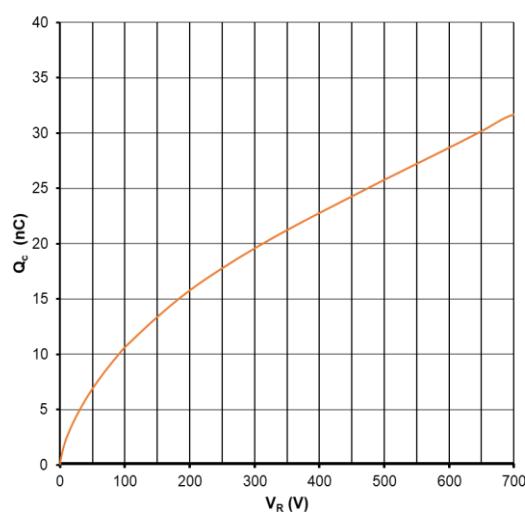
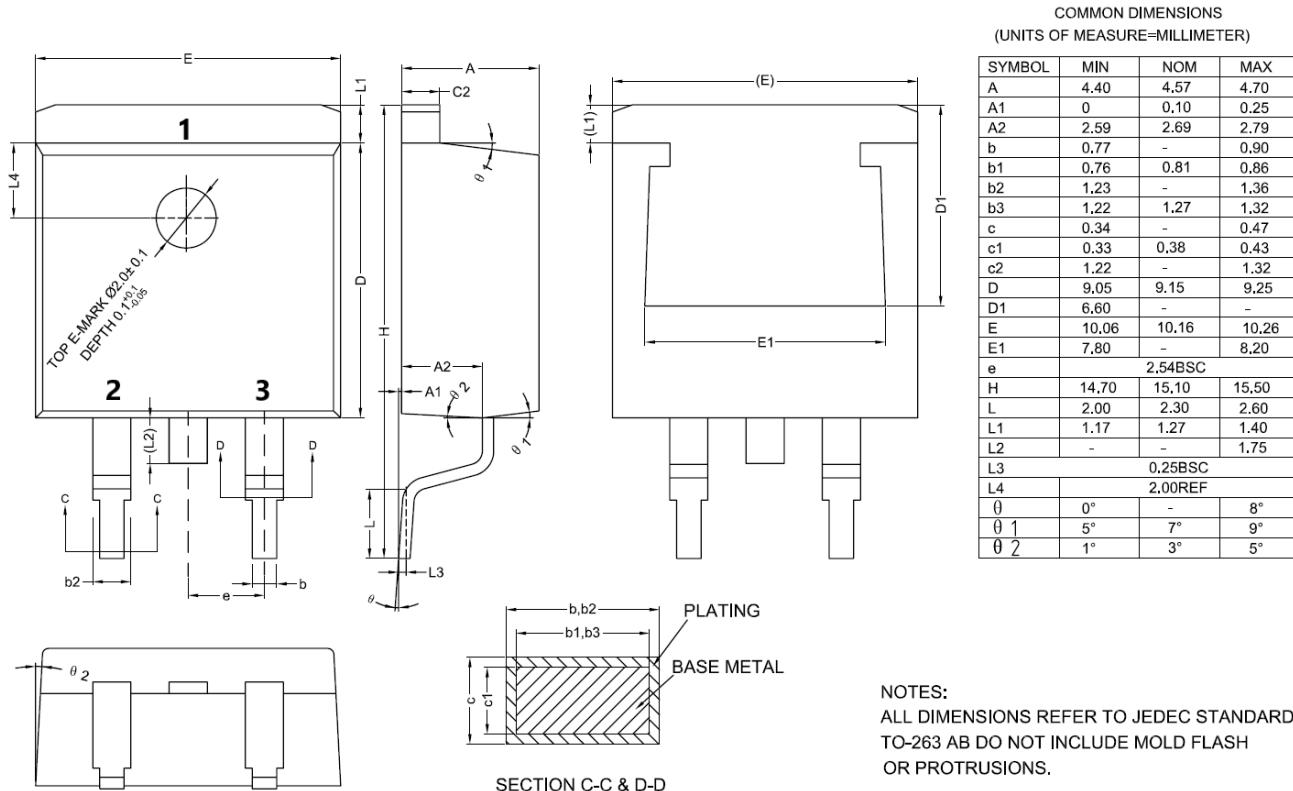


Figure 6. Recovery Charge vs Reverse Voltage



## Package Dimensions

( D<sup>2</sup>PAK Package)



## Ordering Information

Part Number	Package	Packing	Marking	Base Quantity
KN3D10065E	D <sup>2</sup> PAK TO-263-2L	Tape & Reel	KN3D10065E	800